UMENTS

Data sheet acquired from Harris Semiconductor SCHS193A

January 1998 - Revised May 2003

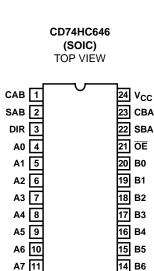
NOT RECOMMENDED FOR NEW DESIGNS **High-Speed CMOS Logic Octal Bus Transceiver/Register, Three-State**

CD74HC646

Features

- · Independent Registers for A and B Buses
- Non-Inverting
- Three-State Outputs
- Drives 15 LSTTL Loads
- Typical Propagation Delay = 12ns (A to B, B to A) at $V_{CC} = 5V, C_1 = 15pF, T_A = 25^{\circ}C$
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: NIL = 30%, NIH = 30% of V_{CC} at $V_{CC} = 5V$

Pinout



GND 12

Description

The CD74HC646 is an octal bus transceiver/register with three-state non-inverting outputs. This device is a bus transceiver with D-type flip-flops which act as internal storage registers. Data on the A bus or the B bus can be clocked into the registers on the Low-to-High transition of either CAB or CBA clock inputs. Outputs enable (\overline{OE}) and direction (DIR) inputs control the transceiver functions. Data present at the high impedance output can be stored in either register or both but only one of the two buses can be enabled as outputs at any one time. The select controls (SAB and SBA) can multiplex stored and transparent (real time) data. The direction control determines which data bus will receive data when the output enable (\overline{OE}) is Low. In the high impedance mode (output enable High), A data can be stored in one register and B data can be stored in the other register. The clocks are not gated with the direction (DIR) and output enable (OE) terminals: data at the A or B terminals can be clocked into the storage flip-flops at any time.

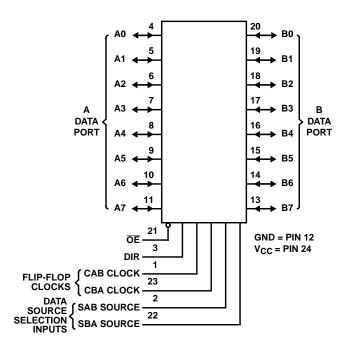
Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD74HC646M	-55 to 125	24 Ld SOIC
CD74HC646M96	-55 to 125	24 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

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Functional Diagram



FUNCTION TABLE

		INP	UTS			Data I/O	(NOTE 1)	
ŌE	DIR	САВ	СВА	SAB	SBA	A0 THRU A7	B0 THRU B7	OPERATION OR FUNCTION
Х	Х	\uparrow	Х	Х	Х	Input	Not Specified	Store A, B Unspecified
Х	Х	Х	\uparrow	Х	Х	Not Specified	Input	Store B, A Unspecified
н	х	\uparrow	Ŷ	Х	Х	Input	Input	Store A and B Data
н	х	H or L	H or L	Х	Х			Isolation, Hold Storage
L	L	Х	Х	Х	L	Output	Input	Real-Time B Data to A Bus
L	L	Х	H or L	Х	н			Stored B Data to A Bus
L	н	Х	Х	L	Х	Input	Output	Real-Time A Data to B Bus
L	Н	H or L	Х	Н	Х			Stored A Data to B Bus

NOTE:

 The data output functions may be enabled or disabled by various signals at the OE and DIR inputs. Data inputs functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs. To prevent excess currents in the High-Z modes all I/O terminals should be terminated with 10kΩ resistors.

Absolute Maximum Ratings

DC Supply Voltage, V _{CC}	/
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$ ±20mA	۲
DC Output Diode Current, I _{OK}	
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	ł
DC Drain Current, per Output, I _O	
For -0.5V < V _O < V _{CC} + 0.5V±35mA	ł
DC Output Source or Sink Current per Output Pin, IO	
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$	ł
DC V _{CC} or Ground Current, I _{CC} ±50mA	ł

Operating Conditions

Temperature Range, T _A
Supply Voltage Range, V _{CC}
HC Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical)	θ _{JA} (^o C/W)
M (SOIC) Package (Note 2)	. 46
Maximum Junction Temperature	150 ⁰ C
Maximum Storage Temperature Range	65 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS		v _{cc}		25 ⁰ C		-40 ^о С т	O 85°C	-55°C T		
PARAMETER	SYMBOL	V _I (V)	l _O (mA)	(Ŭ)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V_{IH} or V_{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CIMOS Loads			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
ITL LUQUS			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
CIMOS LOAUS			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
TTL LUAUS			7.8	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II.	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA
Three-State Leakage Current	I _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5	-	±10	μA

			25 ⁰ C			-40	°C TO 8	5°C	-55°C TO 125°C			
PARAMETER	SYMBOL	V _{CC} (V)	MIN	ТҮР	MAX	MIN	ТҮР	МАХ	MIN	ТҮР	МАХ	UNITS
HC TYPES												
Maximum Frequency	f _{MAX}	2	6	-	-	5	-	-	4	-	-	MHz
		4.5	30	-	-	25	-	-	20	-	-	MHz
		6	35	-	-	29	-	-	23	-	-	MHz
Setup Time Data to Clock	tsu	2	60	-	-	75	-	-	90	-	-	ns
		4.5	12	-	-	15	-	-	18	-	-	ns
		6	10	-	-	13	-	-	15	-	-	ns
Hold Time Data to Clock	tн	2	35	-	-	45	-	-	55	-	-	ns
		4.5	7	-	-	9	-	-	11	-	-	ns
		6	6	-	-	8	-	-	9	-	-	ns
Clock Pulse Width	t _W	2	80	-	-	100	-	-	120	-	-	ns
		4.5	16	-	-	20	-	-	24	-	-	ns
		6	14	-	-	17	-	-	20	-	-	ns

Prerequisite for Switching Specifications

Switching Specifications $C_L = 50 pF$, Input t_r , $t_f = 6 ns$

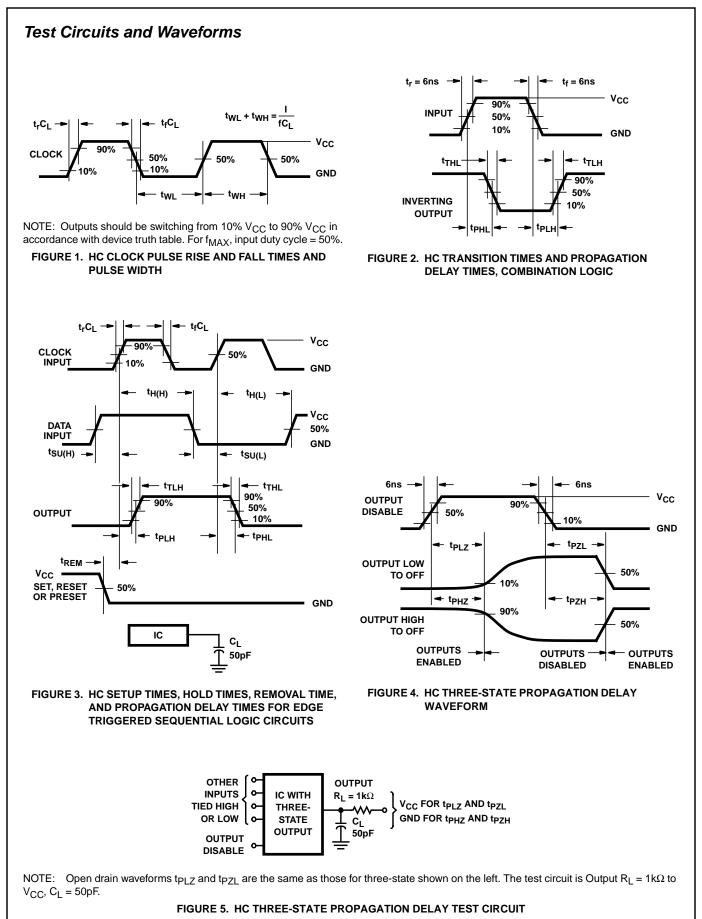
		TEAT			25 ⁰ C			с то ⁰С		С ТО 5⁰С	
PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	МАХ	
HC TYPES											
Propagation Delay	t _{PHL} , t _{PLH}	C _L = 50pF									
Store A Data to B Bus Store B Data to B Bus			2	-	-	220	-	275	-	330	ns
			4.5	-	-	44	-	55	-	66	ns
		C _L = 15pF	5	-	18	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	37	-	47	-	56	ns
A Data to B Bus	^t PLH, ^t PHL	C _L = 50pF	2	-	-	135	-	170	-	205	ns
B Data to A Bus			4.5	-	-	27	-	34	-	41	ns
		C _L = 15pF	5	-	12	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	23	-	29	-	35	ns
Select to Data	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	-	170	-	215	-	255	ns
			4.5	-	-	34	-	43	-	51	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	29	-	37	-	43	ns

		TEOT		25 ⁰ C		-40 ^о С ТО 85 ^о С		-55°C TO 125°C			
PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	МАХ	UNITS
Three-State Disabling Time Bus to Output or Register to	t _{PLZ} , t _{PHZ}	$C_L = 50 pF$	2	-	-	175	-	220	-	265	ns
Output			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Three-State Enabling Time Bus to Output or Register to Output	t _{PZL} , t _{PZH}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	60	-	75	-	90	ns
			4.5	-	-	12	-	15	-	18	ns
		C _L = 50pF	6	-	-	10	-	13	-	15	ns
Input Capacitance	C _{IN}	C _L = 50pF	-	10	-	10	-	10	-	10	pF
Three-State Output Capacitance	C _O	-	-	-	-	20	-	20	-	20	pF
Maximum Frequency	f _{MAX}	C _L = 15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	52	-	-	-	-	-	pF

Switching Specifications 50nE li 6, 10 ...

NOTES:

3. C_{PD} is used to determine the dynamic power consumption, per package. 4. $P_D = V_{CC}^2 C_{PD} f_i \Sigma V_{CC}^2 C_L f_o$ where f_i = Input Frequency, f_o = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.



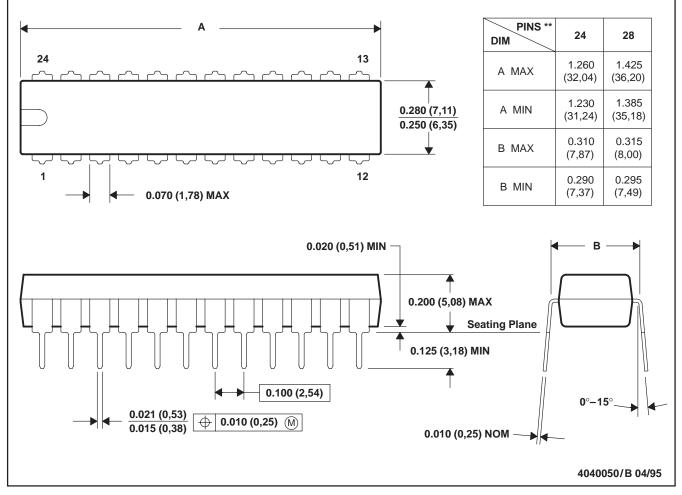
MECHANICAL DATA

MPDI004 - OCTOBER 1994

NT (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters). B. This drawing is subject to change without notice.



DW (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



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